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# **BC214L**

## **PNP General Purpose Amplifier**

- This device is deisgned for use as general purpose amplifiers and switches requiring collector currents to 300mA.
- Sourced from process 68.



1. Emitter 2. Collector 3. Base

# **Absolute Maximum Ratings\*** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	-30	V
V <sub>CBO</sub>	Collector-Base Voltage	-45	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V
I <sub>C</sub>	Collector Current (DC) Continuous	-500	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

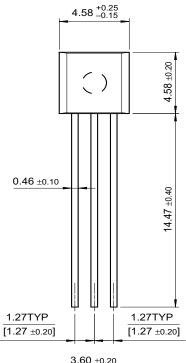
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	eristics	•			
V <sub>(BR)CEO</sub>	Collector-Emitter Voltage	$I_{C} = -2mA, I_{B} = 0$	-30		V
V <sub>(BR)CBO</sub>	Collector-Base Voltage	$I_{C} = -10\mu A, I_{E} = 0$	-45		V
V <sub>(BR)EBO</sub>	Emitter-Base Voltage	$I_E = -10\mu A, I_C = 0$	-5.0		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -30V, I <sub>E</sub> = 0		-15	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = -4V, I <sub>C</sub> = 0		-15	nA
On Characte	eristics *	•			
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ = -5V, $I_{C}$ = -10 $\mu$ A $V_{CE}$ = -5V, $I_{C}$ = -2mA $V_{CE}$ = -5V, $I_{C}$ = -100mA	100 140 120	400	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA		-0.25 -0.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA		-1.1	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = -5V, I_{C} = -2mA$	-0.6	-0.72	V
Small Signa	I Characteristics	•			
f <sub>T</sub>	Current gain Bandwidth Product	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA f = 100MHz	200		MHz
NF	Noise Figure	$V_{CE}$ = -5V, $I_{C}$ = -200μA $R_{G}$ = 2k $\Omega$ , $f$ = 15.7KHz		2.0	dB
h <sub>fe</sub>	Small Signal Current Gain	$I_C = -2mA$ , $V_{CE} = -5V$ f = 1KHz	140		
C <sub>OB</sub>	Output Capacitance	V <sub>CB</sub> = -10V, f = 1MHz		10	pF

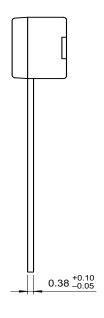
\* Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2.0%

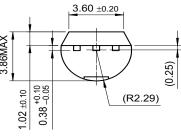
Thermal Characteristics T <sub>A</sub> =25°C unless otherwise noted			
Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

# **Package Dimensions**

TO-92







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FACT™	ISOPLANAR™	OPTOLOGIC®	SMART START™	
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Programmable Ad	ctive Droop™	POP™	SuperSOT™-3	

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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